onsemi

NPN Transistor, 100 V, 3.0 A, Low V_{CE(sat)} NSS1C301ET4G

onsemi's e²PowerEdge family of low $V_{CE(sat)}$ transistors are surface mount devices featuring ultra low saturation voltage ($V_{CE(sat)}$) and high current gain capability. These are designed for use in low voltage, high speed switching applications where affordable efficient energy control is important.

Typical applications are DC–DC converters and power management in portable and battery powered products such as cellular and cordless phones, PDAs, computers, printers, digital cameras and MP3 players. Other applications are low voltage motor controls in mass storage products such as disc drives and tape drives. In the automotive industry they can be used in air bag deployment and in the instrument cluster. The high current gain allows e²PowerEdge devices to be driven directly from PMU's control outputs, and the Linear Gain (Beta) makes them ideal components in analog amplifiers.

Features

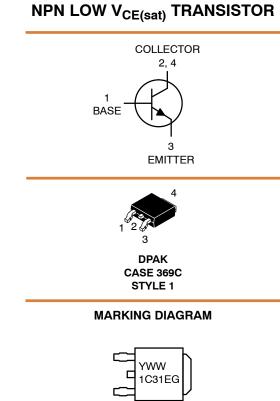
- Complement to NSS1C300ET4G
- NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free and are RoHS Compliant

MAXIMUM RATINGS $(I_A = 25^{\circ}C)$			
Rating	Symbol	Max	Unit
Collector-Base Voltage	V _{CBO}	140	Vdc
Collector-Emitter Voltage	V _{CEO}	100	Vdc
Emitter-Base Voltage	V _{EB}	6.0	Vdc
Collector Current – Continuous	Ι _C	3.0	Adc
Collector Current – Peak	I _{CM}	6.0	Adc
Base Current	Ι _Β	0.5	Adc
Total Power Dissipation @ T _C = 25°C Derate above 25°C	P _D	33 0.26	W W/°C
Total Power Dissipation (Note 1) @ T _A = 25°C Derate above 25°C	P _D	2.1 0.017	W W/°C
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-65 to +150	°C

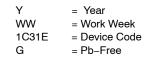
MAXIMUM RATINGS $(T_A = 25^{\circ}C)$

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. These ratings are applicable when surface mounted on the minimum pad sizes recommended.



100 VOLTS, 3.0 AMPS 12.5 WATTS



ORDERING INFORMATION

Device	Package	Shipping [†]
NSS1C301ET4G	DPAK (Pb-Free)	2500/ Tape & Reel
NSV1C301ET4G	DPAK (Pb–Free)	2500/ Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

NSS1C301ET4G

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	3.8	°C/W
Thermal Resistance, Junction-to-Ambient (Note 2)	$R_{\theta JA}$	59.5	°C/W

2. These ratings are applicable when surface mounted on the minimum pad sizes recommended.

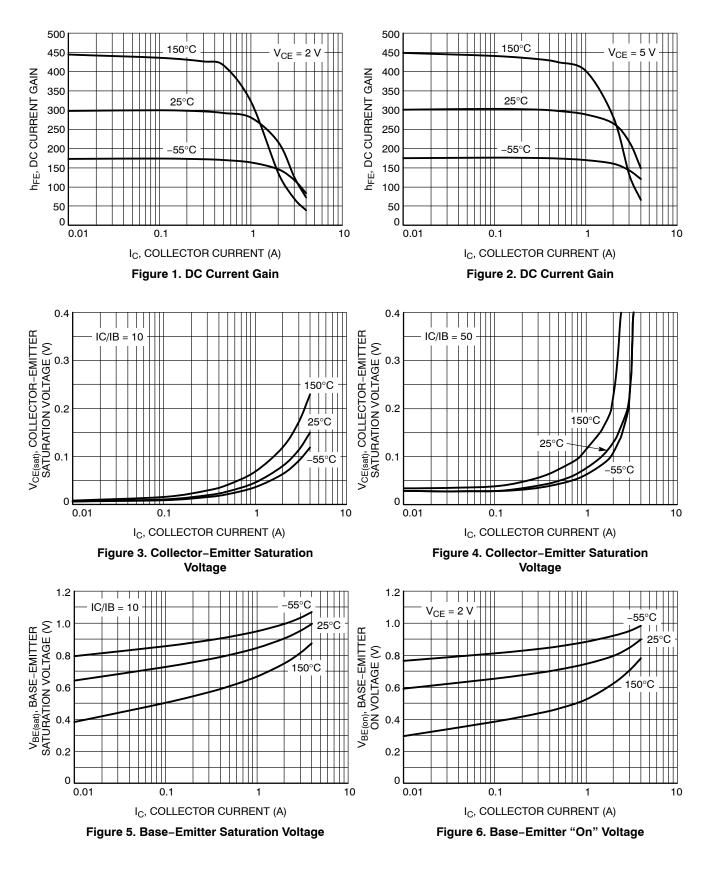
ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Тур	Мах	Unit
OFF CHARACTERISTICS	• • • •				•
Collector – Emitter Breakdown Voltage ($I_C = 10 \text{ mA}, I_B = 0$)	V _{(BR)CEO}	100	_	_	V
Collector – Base Breakdown Voltage $(I_{C} = 0.1 \text{ mA}, I_{E} = 0)$	V _{(BR)CBO}	140	-	_	V
Emitter – Base Breakdown Voltage ($I_E = 0.1 \text{ mA}, I_C = 0$)	V _{(BR)EBO}	6.0	_	-	V
Collector Cutoff Current (V _{CB} = 140 V, I _E = 0)	I _{CBO}	_	-	0.1	μΑ
Emitter Cutoff Current (V _{EB} = 6.0 V)	I _{EBO}	_	-	0.1	μΑ
ON CHARACTERISTICS					
DC Current Gain (Note 3) ($I_C = 0.1 A$, $V_{CE} = 2.0 V$) ($I_C = 0.5 A$, $V_{CE} = 2.0 V$) ($I_C = 1.0 A$, $V_{CE} = 2.0 V$) ($I_C = 3.0 A$, $V_{CE} = 2.0 V$)	h _{FE}	200 200 120 80		_ _ 360 _	_
Collector – Emitter Saturation Voltage (Note 3) ($I_C = 0.1 A$, $I_B = 10 mA$) ($I_C = 1.0 A$, $I_B = 0.100 A$) ($I_C = 2.0 A$, $I_B = 0.200 A$) ($I_C = 3.0 A$, $I_B = 0.300 A$)	V _{CE(sat)}	- - -	0.015 0.045 0.080 0.115	0.050 0.090 0.150 0.250	V
Base – Emitter Saturation Voltage (Note 3) $(I_C = 1.0 \text{ A}, I_B = 0.1 \text{ A})$	V _{BE(sat)}	-	-	1.0	V
Base – Emitter Turn–on Voltage (Note 3) (I _C = 1.0 A, V _{CE} = 2.0 V)	V _{BE(on)}	_	-	0.90	V
Cutoff Frequency (I _C = 500 mA, V _{CE} = 10 V, f = 100 MHz)	f _T	_	120	-	MHz
Input Capacitance (V _{EB} = 5.0 V, f = 1.0 MHz)	Cibo	_	360	-	pF
Output Capacitance (V _{CB} = 10 V, f = 1.0 MHz)	Cobo	_	30	-	pF

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 3. Pulsed Condition: Pulse Width = $300 \ \mu s$, Duty Cycle $\leq 2\%$.

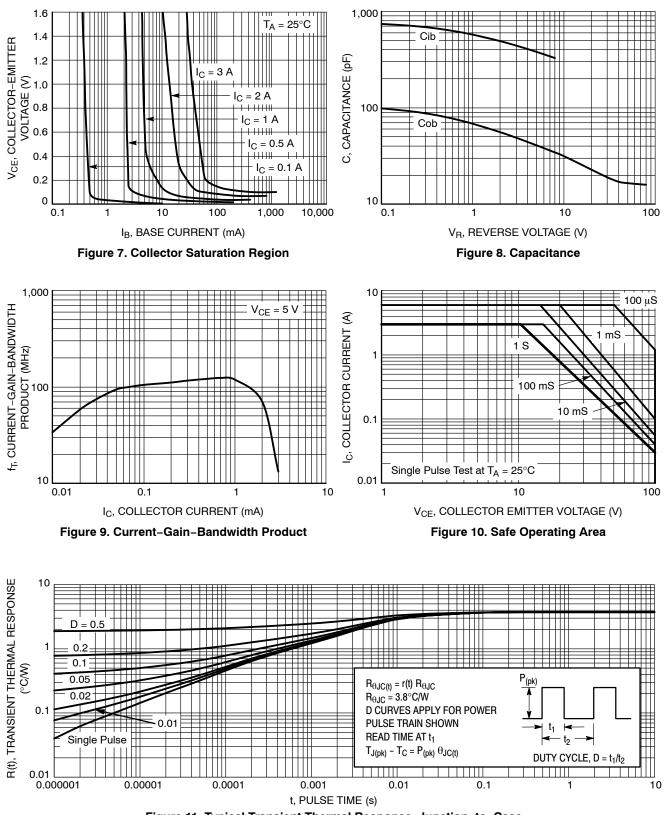
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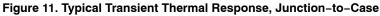
TYPICAL CHARACTERISTICS



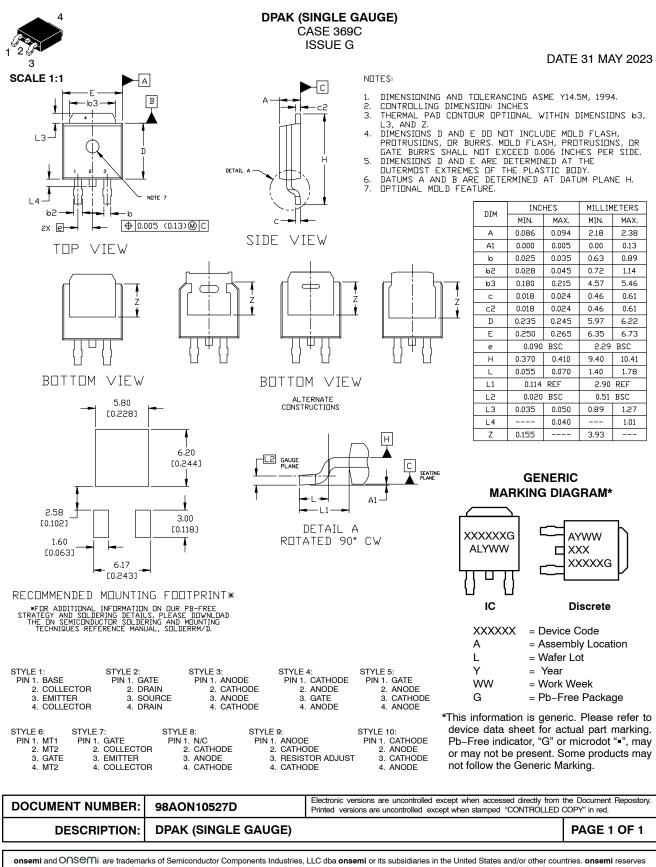
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TYPICAL CHARACTERISTICS





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TECHNICAL PUBLICATIONS:

Technical Library: www.onsemi.com/design/resources/technical-documentation onsemi Website: www.onsemi.com

ONLINE SUPPORT: <u>www.onsemi.com/support</u> For additional information, please contact your local Sales Representative at <u>www.onsemi.com/support/sales</u>

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